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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Obsolete
Core Processor	-
Core Size	16-Bit
Speed	16MHz
Connectivity	CANbus, SPI
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	7
Program Memory Size	64KB (32K x 16)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 16
Voltage - Supply (Vcc/Vdd)	2.25V ~ 3.6V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	40-WFQFN Exposed Pad
Supplier Device Package	40-TQFN (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/analog-devices/maxq7670atl-t

Email: info@E-XFL.COM

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ABSOLUTE MAXIMUM RATINGS

MAXQ7670

DVDD to DGND DVDDIO to GNDIO	
AVDD to AGND	
DGND to GNDIO.	0.3V to +0.3V
GNDIO to AGND.	0.3V to +0.3V
AGND to DGND	0.3V to +0.3V
Analog Inputs to AGND	0.3V to (V _{AVDD} + 0.3V)
RESET, Digital Inputs/Outputs to	
GNDIO	0.3V to (V _{DVDDIO} + 0.3V)
XIN, XOUT to DGND	0.3V to (V _{DVDD} + 0.3V)

Continuous Power Dissipation ($T_A = +70^{\circ}C$)

40-Pin TQFN (derate 36mW/°C al	bove +70°C)
Continuous Current into Any Pin	±50mA
Operating Temperature Range	40°C to +125°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{DVDDIO} = +5.0V, V_{AVDD} = +3.3V, V_{DVDD} = +2.5V, V_{REFADC} = +3.3V, system clock = 16MHz. T_A = T_{MIN}$ to T_MAX, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
POWER REQUIREMENTS		· · · ·				
	DVDD	$\label{eq:regenerative} \overline{\text{REGEN2}} = \text{DVDDIO}, \ \text{DV}_{\text{DD}} \leq \text{AV}_{\text{DD}}, \\ \text{DV}_{\text{DD}} \leq \text{DV}_{\text{DDIO}}$	2.25	2.5	2.75	- V
Supply Voltage Ranges	AVDD	$LRAPD = 1, AV_{DD} \leq DV_{DDIO}$	3.0	3.3	3.6	v
	DVDDIO		4.5	5.0	5.25	
AVDD Supply Current	Iavdd	Shutdown (Note 2)		3	10	μA
	IAVDD	All analog functions enabled		6	7	mA
		ADC, 50ksps, 4MHz ADCCLK		5200		
Analog Module Incremental		ADC, 250ksps, 4MHz ADCCLK		5600		μA
Subfunction Supply Current		AVDD brownout interrupt monitor		3		μΑ
		PGA enabled		5500		
		CPU in stop mode, all peripherals disabled		25	200	μA
		High speed/2MHz mode (Note 3)		2.0	2.5	
DVDD Supply Current	IDVDD	High speed/16MHz mode (Note 4)		11.3		
		Low speed/625kHz mode (Note 5)		0.95		mA
		Program flash erase or write		14	23	7
		DVDDIO brownout reset monitor		1		
Digital Peripheral Incremental Subfunction Supply Current	ΔI_{DVDD}	HF crystal oscillator		60		μA
Sublutietton Supply Current		Internal fixed-frequency oscillator		50		
		All digital I/Os static at GNDIO or DV _{DDIO}		2	20	μA
DVDDIO Supply Current	IDVDDIO	CAN transmitting, timer output switching (Note 6)		0.2	0.3	mA

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DVDDIO} = +5.0V, V_{AVDD} = +3.3V, V_{DVDD} = +2.5V, V_{REFADC} = +3.3V, system clock = 16MHz. T_A = T_{MIN}$ to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

MEMORY SECTIONFlash Memory SizeProgram or data storageFlash Page Size16-bit word sizeFlash Erase/Write EnduranceProgram or data (Note 7)10,000Flash Data Retention (Note 7)All flash, TA = +25°C100Flash Data Retention (Note 7)All flash, TA = +85°C15Flash Erase TimeFlash page erase20Flash Programming TimeFlash single word programming20RAM Memory SizeIntire flash programming0.66	64 256	50 500 40	KB Words Cycles Years ms
Flash Page Size16-bit word sizeFlash Erase/Write EnduranceProgram or data (Note 7)10,000Flash Data Retention (Note 7)All flash, $T_A = +25^{\circ}C$ 100Flash Data Retention (Note 7)All flash, $T_A = +85^{\circ}C$ 15Flash Erase TimeFlash page erase20Flash Programming TimeFlash single word programming20Entire flash programming0.66	256	500 40	Words Cycles Years ms
Flash Erase/Write EnduranceProgram or data (Note 7)10,000Flash Data Retention (Note 7)All flash, $T_A = +25^{\circ}$ C100All flash, $T_A = +85^{\circ}$ C15Flash Erase TimeFlash page erase20Flash Programming TimeFlash single word programming20Entire flash programming0.66		500 40	Cycles Years ms
Flash Data Retention (Note 7)All flash, $T_A = +25^{\circ}C$ 100Flash Data Retention (Note 7)All flash, $T_A = +85^{\circ}C$ 15Flash Erase TimeFlash page erase20Flash Programming TimeFlash single word programming20Entire flash programming20Entire flash programming0.66		500 40	- Years - ms
Flash Data Retention (Note 7)All flash, $T_A = +85^{\circ}C$ 15Flash Erase TimeFlash page erase20Entire flash mass erase200Flash Programming TimeFlash single word programming20Entire flash programming0.66		500 40	- ms
All flash, $T_A = +85^{\circ}$ C15Flash Erase TimeFlash page erase20Entire flash mass erase200Flash Programming TimeFlash single word programming20Entire flash programming0.66		500 40	- ms
Flash Erase TimeEntire flash mass erase200Flash Programming TimeFlash single word programming20Entire flash programming0.66		500 40	
Entire flash mass erase 200 Flash Programming Time Flash single word programming 20 Entire flash programming 0.66		40	
Flash Programming Time Entire flash programming 0.66	0	-	
Entire flash programming 0.66	2	1 0 1	μs
RAM Memory Size	0	1.31	S
	2		KB
Utility ROM Size 16-bit word size	4		KWords
ANALOG SENSE PATH (Includes PGA and ADC)			
ResolutionNADCNo missing codes10			Bits
PGA gain = $16V/V$, bipolar mode, $V_{IN} = \pm 100mV$, 150.9ksps	±0.5	±1	
Integral Nonlinearity INLADC PGA gain = 1V/V, unipolar mode, V _{IN} = +1.0V, 250ksps	±0.4	±1	- LSB ₁₀
Differential Nonlinearity DNL _{ADC} PGA gain = 1V/V or 16V/V	±0.4	±1	LSB ₁₀
Input-Referred Offset Error Test at $T_A = +25^{\circ}C$, PGA gain = 1V/V or 16V/V	±1	±10	mV
Offset-Error Temperature Coefficient PGA gain = 16V/V, bipolar mode	±2		µV/°C
Gain ErrorPGA gain = 16V/V, bipolar mode, excludes offset and reference error, test at $T_A = +25^{\circ}C$		+2	%
Gain-Error Temperature CoefficientPGA gain = 16V/V, bipolar mode	±5		ppm/°C
Conversion Clock Frequency f _{ADCCLK} f _{SYSCLK} = 8MHz or 16MHz 0.5		4.0	MHz
Sample Rate PGA gain = 16V/V, f _{ADCCLK} = 4MHz PGA gain = 1V/V, f _{ADCCLK} = 4MHz		150.9 250	ksps
Channel Select, Track-and- PGA gain = 16V/V, 13.5 ADCCLK cycles at 4MHz	3.375		
Hold Acquisition Time PGA gain = 1V/V, three ADCCLK cycles at 4MHz	0.75		μs
Conversion Time t _{CONV} 13 ADCCLK cycles at 4MHz	3.25		μs

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DVDDIO} = +5.0V, V_{AVDD} = +3.3V, V_{DVDD} = +2.5V, V_{REFADC} = +3.3V$, system clock = 16MHz. T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Output Capacitance		I/O pins three-state		15		рF
Maximum Output Impedance		PD0 = 0		880		Ω
Maximum Output impedance		PD0 = 1		450		52
SYSTEM CLOCK						
System Clock Frequency	f SYSCLK	From any clock source	0		16.67	MHz
SPI INTERFACE TIMING						
SPI Master Operating Frequency	fMCLK	0.5 x fsysclk			8	MHz
SPI Slave Mode Operating Frequency	^f SCLK				fsysclk/8	MHz
SCLK Output Pulse-Width High/Low	t _{MCH} , t _{MCL}		tsysclk - 25			ns
SCLK Input Pulse-Width High/Low	tSCH, tSCL			t SYSCLK		ns
MOSI Output Hold Time After SCLK Sample Edge	tмон		tsysclk - 25			ns
MOSI Output Setup Time to SCLK Sample Edge	tMOS		tsysclk - 25			ns
MISO Input Setup Time to SCLK Sample Edge	tMIS		30			ns
MISO Input Hold Time After SCLK Sample Edge	tMIH		0			ns
SCLK Inactive to MOSI Inactive	tMLH		tsysclk - 25			ns
MOSI Input Setup Time to SCLK Sample Edge	tsis		30			ns
MOSI Input Hold Time After SCLK Sample Edge	tsiH		tsysclk + 25			ns
MISO Output Valid After SCLK Shift Edge Transition	tsov				3 tsysclk + 25	ns
MISO Output Disabled After SS Edge Rise	^t SLH				2 t _{SYSCLK} + 50	ns
SS Falling Edge to MISO Active	tSOE		2 t _{SYSCLK} + 2.5			ns

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{DVDDIO} = +5.0V, V_{AVDD} = +3.3V, V_{DVDD} = +2.5V, V_{REFADC} = +3.3V, system clock = 16MHz. T_A = T_{MIN} \text{ to } T_{MAX}, unless otherwise noted. Typical values are at T_A = +25^{\circ}C.) (Note 1)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
SS Falling Edge to First SCLK Sample Edge	tsse		2 tsysclk + 5			ns
SCLK Inactive to SS Rising Edge	tsD		tsysclk + 10			ns
Minimum CS Pulse Width	tscw		tsysclk + 10			ns

Note 1: All devices are 100% production tested at $T_A = +25^{\circ}C$ and $+125^{\circ}C$. Temperature limits to $T_A = -40^{\circ}C$ are guaranteed by design.

Note 2: All analog functions disabled and all digital inputs connected to supply or ground.

Note 3: High-speed/8 mode without CAN; V_{DVDD} = +2.5V, CPU and 16-bit timer running at 2MHz from an external, 16MHz crystal oscillator; all other peripherals disabled; all digital I/Os static at V_{DVDDIO} or GNDIO; T_A = T_{MIN} to T_{MAX}.

Note 4: High-speed/1 mode with CAN; V_{DVDD} = +2.5V, CPU and 16-bit timer running at 16MHz from an external, 16MHz crystal oscillator; CAN enabled and communicating at 500kbps; all other peripherals disabled, all digital I/Os (except CANTXD and CANRXD) static at V_{DVDDIO} or GNDIO, T_A = T_{MIN} to T_{MAX}.

Note 5: Low speed, PMM1 mode without CAN; $V_{DVDD} = +2.5V$, CPU and one timer running from an external, 16MHz crystal oscillator in PMM1 mode; all other peripherals disabled; all digital I/Os static at V_{DVDDIO} or GNDIO, $T_A = T_{MIN}$ to T_{MAX} .

Note 6: CAN transmitting at 500kbps; 16-bit timer output switching at 500kHz; all active I/Os are loaded with a 20pF capacitor; all remaining digital I/Os are static at V_{DVDDIO} or GNDIO, $T_A = T_{MIN}$ to T_{MAX} .

Note 7: Guaranteed by design and characterization.

Note 8: This is not a static capacitance. It is the capacitance presented to the analog input when the T/H amplifier is in sample mode.

Note 9: The switched capacitor on the REFADC input can disturb the reference voltage. To reduce this disturbance, place a 0.1µF capacitor from REFADC to AGND as close as possible to REFADC.

Note 10: The digital design is fully static. However, the lower clock limit is set by a clock detect circuit. The MAXQ7670 switches to the internal RC clock if the external input goes below 166kHz. This clock detect circuit also acts to detect a crystal failure when a crystal is used.

MAXQ7670

Table 5. Peripheral Register Bit Functions and Reset Values (continued)

										,						
REGISTER	15	14	13	12	11	10	6	REGISTER BIT		9	5	4	ę	2	-	0
	1	:	!	!	CRTMS	CRTM	TESTCAN		DCW	FTEST	DOFF	· I	SRT	.	SCANMODE	TME
¥ ₽	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
UUU	I	I	I						ERIE	STIE	PDE	SIESTA	CRST	AUTOB	ERCS	SWINT
2002	0	0	0	0	0	0	0	0	0	0	0	0	1	0	0	1
000	I								SSB	EC96/128	WKS	SXR	TXS	ER2	ER1	ERO
en:	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
	I								ZNITNI	INTIN6	INTIN5	1NTIN4	INTIN3	INTIN2	INTIN1	INTINO
HINO	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
LEOC	I	I	I						COTE.7	COTE.6	COTE.5	COTE.4	COTE.3	COTE.2	COTE.1	COTE.0
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
1000									CORE.7	CORE.6	CORE.5	CORE.4	CORE.3	CORE.2	CORE.1	CORE.0
CUHE	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
0	1				I	I	I	I	CANOBA	INCDEC	AID	C0BPR7	COBPR6		COBIE	COIE
HUU	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
	CODP.15	C0DP.14	C0DP.13	C0DP.12	C0DP.11	C0DP.10	CODP.9	CODP.8	CODP.7	CODP.6	CODP.5	CODP.4	CODP.3	CODP.2	CODP.1	CODP.0
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
	CODB.15	CODB.14	C0DB.13	C0DB.12	C0DB.11	CODB.10	CODB.9	CODB.8	C0DB.7	CODB.6	CODB.5	C0DB.4	CODB.3	C0DB.2	C0DB.1	CODB.0
CUUB	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
011000	I	CORMS.15	CORMS.14	CORMS.13	CORMS.12	CORMS.11	CORMS.10	CORMS.9	CORMS.8	CORMS.7	CORMS.6	CORMS.5	CORMS.4	CORMS.3	CORMS.2	CORMS.1
CUHINS	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
ODTMAN	I	COTMA. 15	COTMA.14	COTMA.13	C0TMA.12	COTMA.11	C0TMA.10	COTMA.9	COTMA.8	C0TMA.7	COTMA.6	C0TMA.5	COTMA.4	C0TMA.3	COTMA.2	COTMA.1
MINIO	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
CIMIC									MSRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
COMOC									MSRDY	ETI	ERI	INTRQ	extro	MTRQ	ROW/TIH	DTUP
COMICO	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
		_	_						MSRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
00000	I	I	I			I			MSRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
000150	I								YORRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
CONJEC	Ι								MSRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
COMIZC	I	I	I			I			MSRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
COMBC		I	I			I			MSRDY	ETI	ERI	INTRQ	extro	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
COMAC					_	-	-		MSRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
DEMINO.	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
COMINC	I								MSRDY	ETI	ERI	INTRQ	extro	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
COM11C						I			MSRDY	ETI	ERI	INTRQ	extro	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
COM12C	1	l	l		I	1		I	MSRDY	ETI	ERI	INTRQ	EXTRQ	MTRQ	ROW/TIH	DTUP
	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0

Microcontroller with 10-Bit ADC, PGA, 64KB Flash, and CAN Interface

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